MA21D38

Silicon epitaxial planar type

For high frequency rectification

■ Features

- $I_{F(AV)} = 1$ A rectification is possible
- Low forward voltag V_F
- High non-repetitive peak forward surge voltage

■ Absolute Maximum Ratings $T_a = 25$ °C

| Parameter | Symbol | Rating | Unit | | | | |
|---|--------------------|-------------|------|--|--|--|--|
| Reverse voltage | V _R | 30 | V | | | | |
| Maximum peak reverse voltage | V _{RM} | 30 | V | | | | |
| Forward current (Average) | I _{F(AV)} | 1.0 | A | | | | |
| Non-repetitive peak forward surge current * | I _{FSM} | 20 | A | | | | |
| Junction temperature | T _j | 125 | °C | | | | |
| Storage time | T _{stg} | -55 to +125 | °C | | | | |

Note) *: The peak-to-peak value in one cycle of 50 Hz sine wave (non-repetitive)

Unit: mm 0.60±0.10 0.80±0.10 0

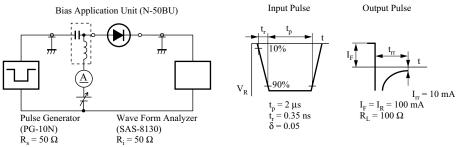
Marking Symbol: 3U

■ Electrical Characteristics $T_a = 25$ °C±3°C

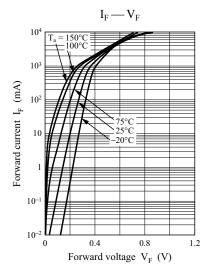
| Parameter | Symbol | Conditions | Min | Тур | Max | Unit |
|-------------------------|-----------------|--|-----|------|------|------|
| Forward voltage | V_{F1} | $I_{\rm F} = 0.5 \text{ A}$ | | 0.34 | 0.38 | V |
| | V _{F2} | $I_F = 0.7 A$ | | 0.36 | 0.40 | |
| | V _{F3} | $I_{\rm F} = 1.0 \text{ A}$ | | 0.38 | 0.42 | |
| Reverse current | I_R | $V_R = 30 \text{ V}$ | | | 100 | μΑ |
| Terminal capacitance | C _t | V _R = 10 V, f = 1 MHz | | 40 | | pF |
| Reverse recovery time * | t _{rr} | $I_F = I_R = 100 \text{ mA}, I_{rr} = 10 \text{ mA},$ $R_L = 100 \Omega$ | | 13 | | ns |

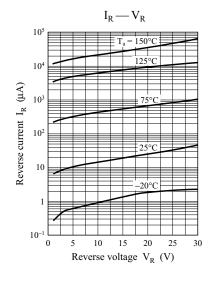
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031 measuring methods for diodes.

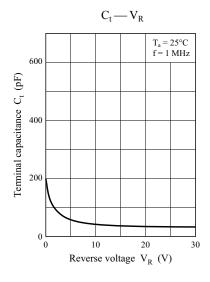
- 2. This product is sensitive to electric shock (static electricity, etc.). Due attention must be paid on the charge of a human body and the leakage of current from the operating equipment.
- 3. *: t_{rr} measurement circuit

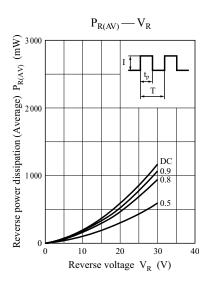


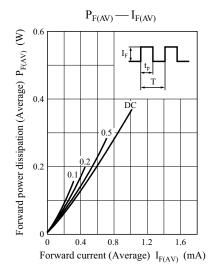
MA21D38 Panasonic

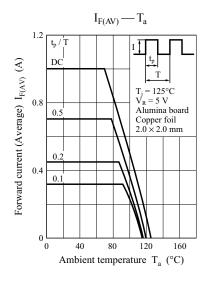


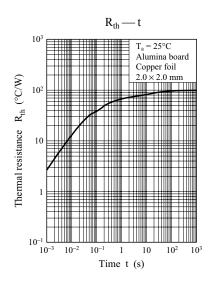












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